



**UMSDXXXGBP**

# **Micro-SD 3.0 Memory Card**

## **Specification**

Version 1.1

### **Revision History**

<b>Revision</b>	<b>History</b>	<b>Draft Date</b>	<b>Remark</b>
<b>1.0</b>	<b>First Release</b>	<b>2011-03-21</b>	<b>Andre</b>
<b>1.1</b>	<b>Mechanical Drawing updated</b>	<b>2011-07-01</b>	<b>Eric</b>

## A. General Description

The Micro Secure Digital (Micro SD) card version 3.0 is fully compliant to the specification released by SD Card Association. The Command List supports [Part 1 Physical Layer Specification Ver3.1 Final] definitions. Card Capacity of Non-secure Area, Secure Area Supports [Part 3 Security Specification Ver3.0 Final] Specifications.

The Micro-SD 3.0 card is based on 8-pin interface, designed to operate at a maximum operating frequency of 50MHz or 100MHz. It can alternate communication protocol between the SD mode and SPI mode. It performs data error detection and correction with very low power consumption.

Micro Secure Digital 3.0 card is one of the most popular cards today based on its high performance, good reliability and wide compatibility.

## B. Features

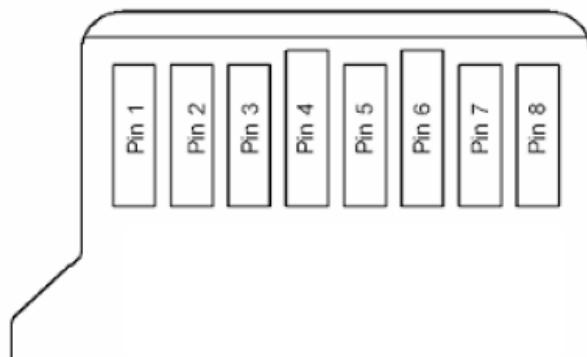
- Support SD system specification version 2.0 and 3.0.
- Card Capacity of Non-secure Area, Secure Area Supports [Part 3 Security Specification Ver3.1 Final] Specifications
- Support SD SPI mode
- Designed for read-only and read/write cards.
- Default mode : Variable clock rate 0-25MHz, up to 12.5MB/sec interface speed
- High-Speed mode : Variable clock rate 0-50MHz, up to 25MB/sec interface speed
- The Command List supports [Part 1 Physical Layer Specification Ver3.1 Final] definitions
- Copyrights Protection Mechanism - Complies with highest security of SDMI standard
- Password Protection of cards (option)
- Built-in write protection features (permanent and temporary)]
- High transmission speed
- +4KV/-4KV ESD protection in contact pads.
- Dimension : 15mm(L) x 11mm(W) x 1mm(H)



## C. Comparison of SD Card

	<b>SD3.0 Standard (Backward compatible to 2.0 host)</b>	<b>SD3.0 SDHC (Backward compatible to 2.0 host)</b>
<b>Addressing Mode</b>	Byte (1 byte unit)	Block (512 byte unit)
<b>HCS/CCS bits of ACMD41</b>	Support	Support
<b>CMD8 (SEND_IF_COND)</b>	Support	Support
<b>CMD16 (SET_BLOCKLEN)</b>	Support	Support (Only CMD42)
<b>Partial Read</b>	Support	Not Support
<b>Lock/Unlock Function</b>	Mandatory	Mandatory
<b>Write Protect Groups</b>	Optional	Not Support
<b>Supply Voltage 2.0v – 2.7v (for initialization)</b>	Not Support	Not Support
<b>Total Bus Capacitance for each signal line</b>	40pF	40pF
<b>CSD Version (CSD_STRUCTURE Value)</b>	1.0 (0x0)	2.0 (0x1)
<b>Speed Class</b>	Optional	Mandatory (Class 2/4/6/10 )

## D. Pin Assignment



pin	SD Mode			SPI Mode		
	Name	Type <sup>1</sup>	Description	Name	Type	Description
1	DAT2	I/O/PP	Data Line[bit2]	RSV		
2	CD/DAT3 <sup>2</sup>	I/O/PP <sup>3</sup>	Card Detect/ Data Line[bit3]	CS	I <sup>3</sup>	Chip Select (neg true)
3	CMD	PP	Command/Response	DI	I	Data In
4	V <sub>DD</sub>	S	Supply voltage	V <sub>DD</sub>	S	Supply voltage
5	CLK	I	Clock	SCLK	I	Clock
6	V <sub>SS</sub>	S	Supply voltage ground	V <sub>SS</sub>	S	Supply voltage ground
7	DAT0	I/O/PP	Data Line[bit0]	DO	O/PP	Data Out
8	DAT1	I/O/PP	Data Line[bit1]	RSV		

- (1) S: power supply, I: input; O: output using push-pull drivers; PP: I/O using push-pull drivers
- (2) The extended DAT lines (DAT1-DAT3) are input on power up. They start to operate as DAT lines after SET\_BUS\_WIDTH command. The Host shall keep its own DAT1-DAT3 lines in input mode, as well, while they are not used. It is defined so, in order to keep compatibility to Multimedia Cards.
- (3) At power up this line has a 50KOhm pull up enabled in the card. This resistor serves two functions Card detection and Mode Selection. For Mode Selection, the host can drive the line high or let it be pulled high to select SD mode. If the host wants to select SPI mode it should drive the line low. For Card detection, the host detects that the line is pulled high. This pull-up should be disconnected by the user during regular data transfer period , with SET\_CLR\_CARD\_DETECT(ACMD42) command.

Name	Width	Description
CID	128bit	Card identification number; card individual number for identification. <b>Mandatory</b>
RCA1	16bit	Relative card address; local system address of a card, dynamically suggested by the card and approved by the host during initialization. <b>Mandatory</b>
DSR	16bit	Driver Stage Register; to configure the card's output drivers. <b>Optional</b>
CSD	128bit	Card Specific Data; information about the card operation conditions. <b>Mandatory</b>
SCR	64bit	SD Configuration Register; information about the SD Memory Card's Special Features capabilities <b>Mandatory</b>
OCR	32bit	Operation conditions register. <b>Mandatory</b> .
SSR	512bit	SD Status; information about the card proprietary features <b>Mandatory</b>
OCR	32bit	Card Status; information about the card status <b>Mandatory</b>

## E. Power Consumption

Table list as below is the power consumption of SD card with different type of flash memory.

Flash mode	Max Power up Current (uA)	Max Stand by Current (uA)	Max Read Current (mA)	Max Write Current (mA)
Single <sup>(1)</sup> flash(1x8bit)	150	150	100@ 3.6V	100@ 3.6V

(1)Data transfer mode is single channel.

## F. Electrical Specifications

### *Absolute Maximum Rating*

Item	Symbol	Parameter	MIN	MAX	Unit
1	$V_{DD}-V_{SS}$	DC Power Supply	-0.3	+3.3	V
2	$V_{IN}$	Input Voltage	$V_{SS}-0.3$	$V_{DD}+0.3$	V
3	$T_a$	Operating Temperature	0	+70	°C
4	$T_{st}$	Storage Temperature	-25	+85	°C

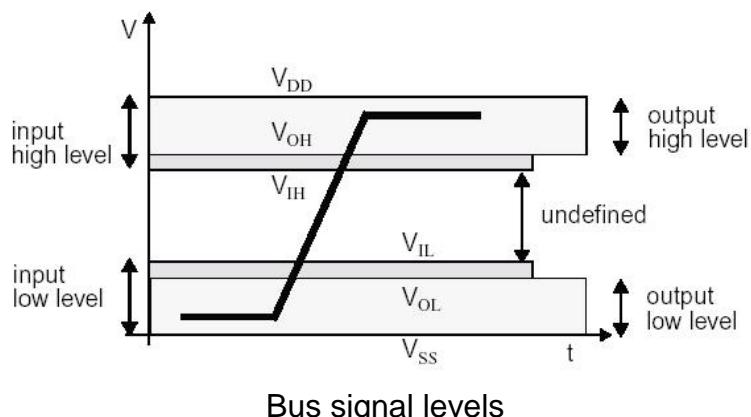
Parameter	Symbol	Min	MAX	Unit
Operating Temperature	$T_a$	0	+70	°C
$V_{DD}$ Voltage	$V_{DD}$	2.7	3.6	V

## G. DC Characteristic

- Threshold level for High Voltage Range

Parameter	Symbol	Min	Max	Unit	Remarks
Supply voltage	$V_{DD}$	2.7	3.6	V	
Output High Voltage	$V_{OH}$	$0.75*V_{DD}$		V	$I_{OH}=-100\mu A$ $V_{DD}$ Min.
Output Low Voltage	$V_{OL}$		$0.125*V_{DD}$	V	$I_{OL}= 100\mu A$ $V_{DD}$ min
Input High Voltage	$V_{IH}$	$0.625*V_{DD}$	$V_{DD}+0.3$	V	
Input Low Voltage	$V_{IL}$	$V_{SS}-0.3$	$0.25 *V_{DD}$	V	
Power up time			250	ms	from 0v to $V_{DD}$ min.

### Bus Signal Levels



- General

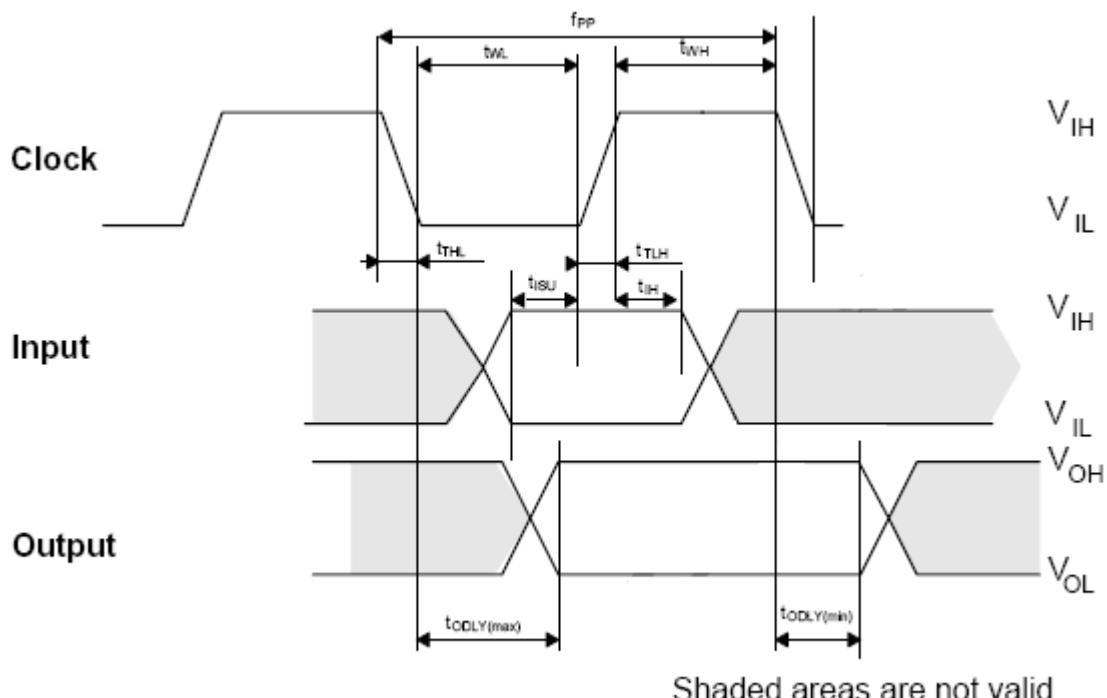
Parameter	Symbol	Min	Max.	Unit	Remarks
Peak voltage on all lines		-0.3	$V_{DD}+0.3$	V	
<b>All Inputs</b>					
Input Leakage Current		-10	10	$\mu A$	
<b>All Outputs</b>					
Output Leakage Current		-10	10	$\mu A$	

- Bus Signal Line Levels

Parameter	symbol	Min	Max	Unit	Remark
Pull-up resistance	$R_{CMD}$ $R_{DAT}$	10	100	kΩ	to prevent bus floating
Total bus capacitance for each signal line	$C_L$		40	pF	1 card $C_{HOST}+C_{BUS}$ shall not exceed 30 pF
Capacitance of the card for each signal pin	$C_{CARD}$		10	pF	
Maximum signal line inductance			16	nH	$f_{pp}<20$ MHz
Pull-up resistance inside card (pin1)	$R_{DAT3}$	10	90	kΩ	May be used for card detection

## H. AC Characteristic

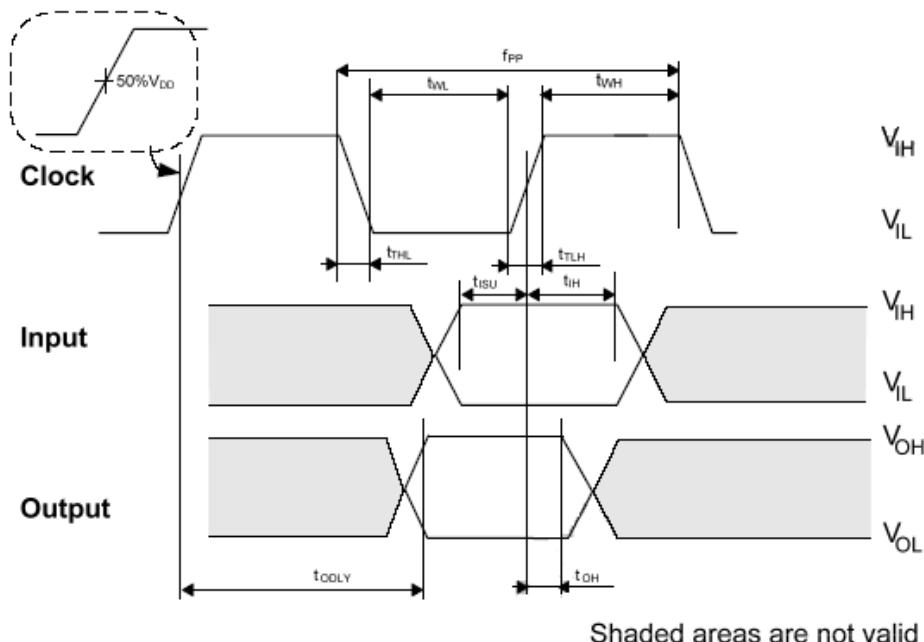
### H1. Micro SD Interface timing (Default)



Shaded areas are not valid

Parameter	Symbol	Min	Max	Unit	Remark
<b>Clock CLK (All values are referred to min(<math>V_{IH}</math>) and max(<math>V_{IL}</math>))</b>					
Clock frequency Data Transfer Mode	$f_{PP}$	0	25	MHz	$C_{card} \leq 10 \text{ pF}$ (1 card)
Clock frequency Identification Mode	$f_{OD}$	$0_{(1)}/100$	400	kHz	$C_{card} \leq 10 \text{ pF}$ (1 card)
Clock low time	$t_{WL}$	10		ns	$C_{card} \leq 10 \text{ pF}$ (1 card)
Clock high time	$t_{WH}$	10		ns	$C_{card} \leq 10 \text{ pF}$ (1 card)
Clock rise time	$t_{TLH}$		10	ns	$C_{card} \leq 10 \text{ pF}$ (1 card)
Clock fall time	$t_{THL}$		10	ns	$C_{card} \leq 10 \text{ pF}$ (1 card)
<b>Inputs CMD, DAT (referenced to CLK)</b>					
Input set-up time	$t_{ISU}$	5		ns	$C_{card} \leq 10 \text{ pF}$ (1 card)
Input hold time	$t_{IH}$	5		ns	$C_{card} \leq 10 \text{ pF}$ (1 card)
<b>Outputs CMD, DAT (referenced to CLK)</b>					
Output Delay time during Data Transfer Mode	$t_{ODLY}$	0	14	ns	$C_L \leq 40 \text{ pF}$ (1 card)
Output Delay time during Identification Mode	$t_{ODLY}$	0	50	ns	$C_L \leq 40 \text{ pF}$ (1 card)

(1) 0Hz means to stop the clock. The given minimum frequency range is for cases were continues clock is required.

**H2. Micro SD Interface timing (High-speed Mode)**


Parameter	Symbol	Min	Max	Unit	Remark
<b>Clock CLK (All values are referred to min(V<sub>IH</sub>) and max(V<sub>IL</sub>))</b>					
Clock frequency Data Transfer Mode	f <sub>PP</sub>	0	50	MHz	C <sub>card</sub> ≤ 10 pF (1 card)
Clock low time	t <sub>WL</sub>	7		ns	C <sub>card</sub> ≤ 10 pF (1 card)
Clock high time	t <sub>WH</sub>	7		ns	C <sub>card</sub> ≤ 10 pF (1 card)
Clock rise time	t <sub>TLH</sub>		3	ns	C <sub>card</sub> ≤ 10 pF (1 card)
Clock fall time	t <sub>THL</sub>		3	ns	C <sub>card</sub> ≤ 10 pF (1 card)
<b>Inputs CMD, DAT (referenced to CLK)</b>					
Input set-up time	t <sub>ISU</sub>	6		ns	C <sub>card</sub> ≤ 10 pF (1 card)
Input hold time	t <sub>IH</sub>	2		ns	C <sub>card</sub> ≤ 10 pF (1 card)

					pF (1 card)
<b>Outputs CMD, DAT (referenced to CLK)</b>					
Output Delay time during Data Transfer Mode	$t_{ODLY}$		14	ns	$C_L \leq 40 \text{ pF}$ (1 card)
Output Hold time	$T_{OH}$	2.5	50	ns	$C_L \leq 15 \text{ pF}$ (1 card)
Total System capacitance of each line <sup>1</sup>	$C_L$		40	pF	$CL \leq 15 \text{ pF}$ (1 card)

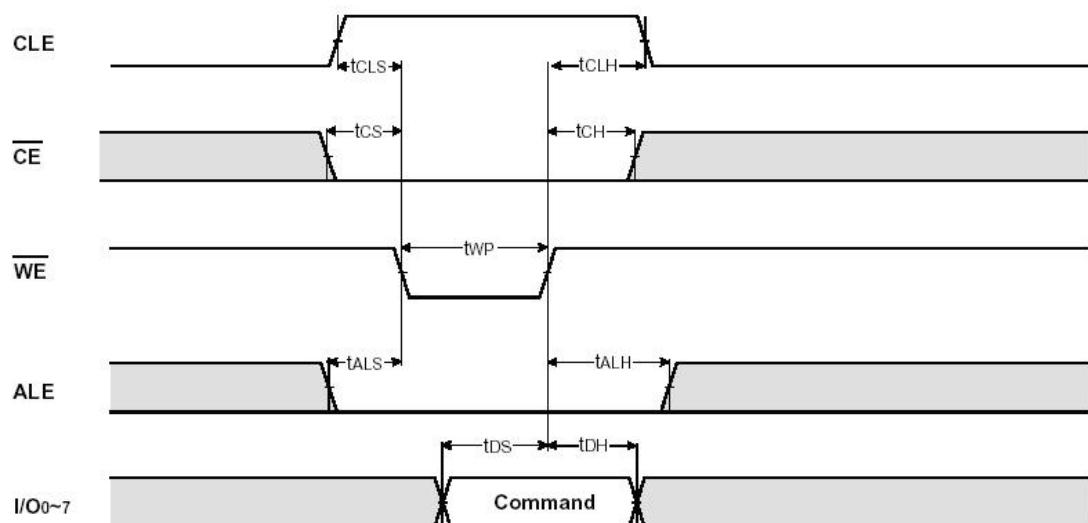
(1) In order to satisfy severe timing, host shall drive only one card.

### H3. Flash Interface AC Characteristic

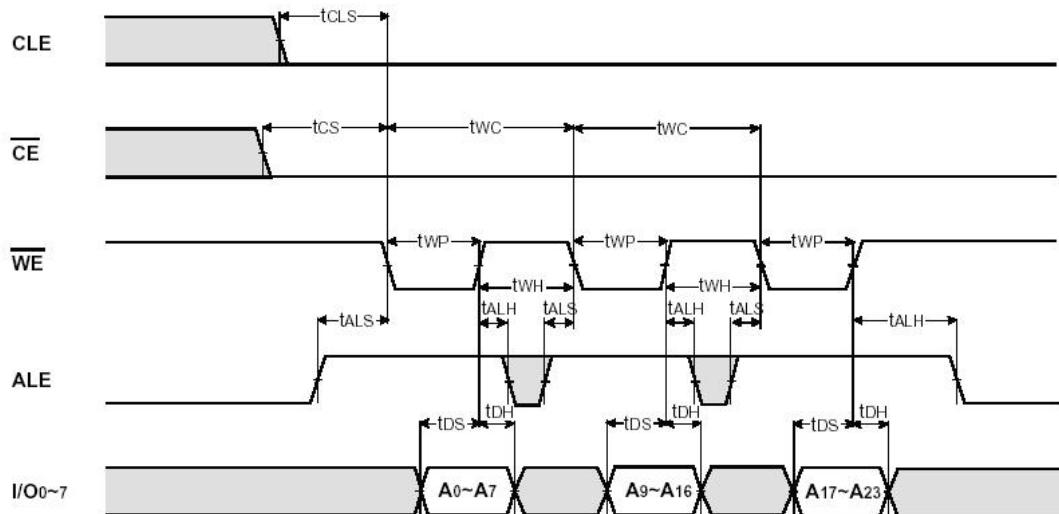
Parameter	Symbol	Min	Max	Unit
CLE Set-up Time	$t_{CLS}$	50	-	ns
CLE Hold Time	$t_{CLH}$	50	-	ns
/CE Setup Time	$t_{CS}$	200	-	ns
/CE Hold Time	$t_{CH}$	200	-	ns
WE Pulse Width	$t_{WP}$	30	50	ns
ALE Setup Time	$t_{ALS}$	50	-	ns
ALE Hold Time	$t_{ALH}$	50	-	ns
Data Setup Time	$t_{DS}$	20	50	ns
Data Hold Time	$t_{DH}$	30	100	ns
Write Cycle Time	$t_{WC}$	50	200	ns
WE High Hold Time	$t_{WH}$	20	150	ns
Read Cycle Time	$t_{RC}$	50	-	ns
/RE Pulse Width	$t_{RP}$	30	-	ns
/RE High Hold Time	$t_{REH}$	20	-	ns
Ready to /RE Low	$t_{RR}$	30	-	ns

### H4. Flash memory timing

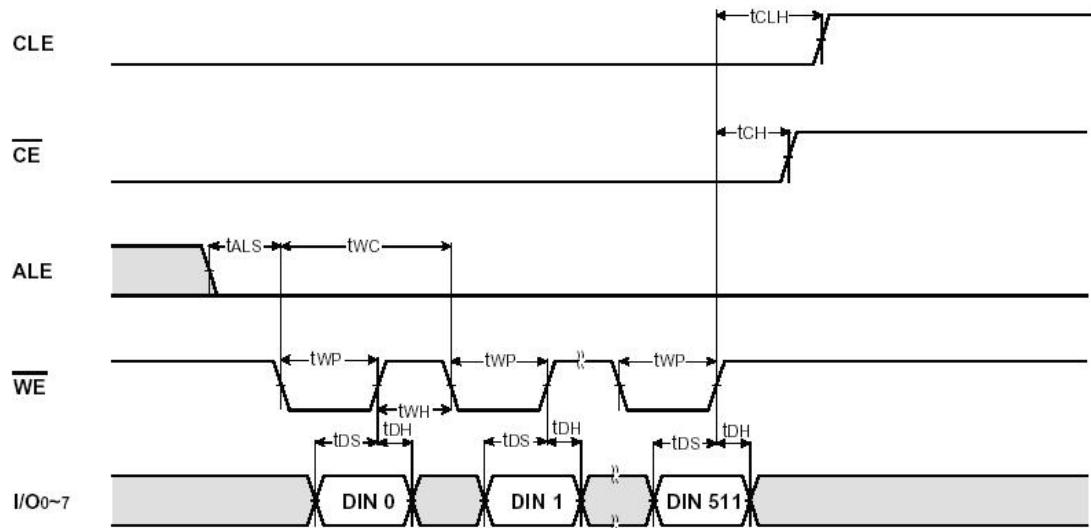
#### (a) Command Latch Cycle



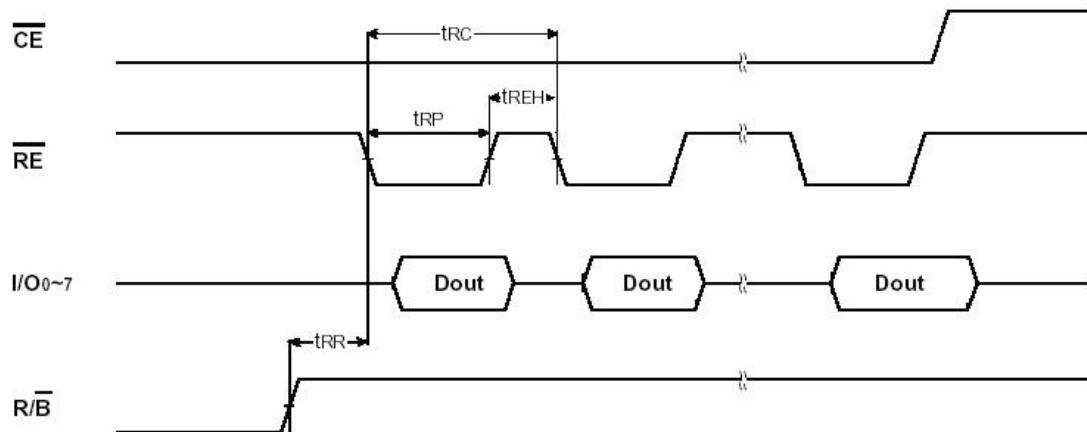
(b) Address Latch Cycle



(c) Input Data Latch Cycle



(d) Sequential Out Cycle after Read (CLE=L, /WE=H, ALE=L)



## I. Part Numbers

Part Number	Description	Operating Temperature
UMSD002GBP	2GB µSD	0°C ~ 70°C
UMSD004GBP	4GB µSD	0°C ~ 70°C
UMSD008GBP	8GB µSD	0°C ~ 70°C
UMSD016GBP	16GB µSD	0°C ~ 70°C
UMSD032GBP	32GB µSD	0°C ~ 70°C

## J. Dimension

